Advanced Packaging Materials and Techniques for High Power TR Module: Standard Flight vs. Advanced Packaging

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Abstract—The higher output power densities required of modern radar architectures, such as the proposed DESDynI [Deformation, Ecosystem Structure, and Dynamics of Ice] SAR [Synthetic Aperture Radar] Instrument (or DSI) require increasingly dense high power electronics. To enable these higher power densities, while maintaining or even improving hardware reliability, requires advances in integrating advanced thermal packaging technologies into radar transmit/receive (TR) modules. New materials and techniques have been studied and compared to standard technologies.

I. INTRODUCTION

New radar systems, such as DSI (the proposed DESDynI [Deformation, Ecosystem Structure, and Dynamics of Ice] Interferometric SAR [Synthetic Aperture Radar]) [1], that employ array fed reflectors, require higher RF power densities than traditional flat panel phased arrays. To enable large numbers of densely-packed, transmit/receive (TR) modules capable of even higher output power, design of the thermal packaging is increasingly more important. This paper details the investigation of new packaging materials and techniques to improve thermal performance to significantly improve reliability while enabling advancements in instrument performance.

High power, compact arrays enable the use of large reflector-based architectures, such as SweepSAR [2], which significantly reduce instrument mass and its associated cost. Higher power, more compact arrays, however, dramatically increase the power density, both RF and DC, due to the smaller size and higher power. Thermal dissipation in these arrays is a key challenge, and requires integrated thermal management to maintain, and possibly improve, overall reliability in the presence of increased thermal variations.

The key benefit of the advanced packaging techniques discussed in this paper is in improving the trade-space between increasingly dense, higher power-handling RF-hybrids and their long term reliability on-orbit. This is accomplished by reducing thermal cycling stress through more efficient electronics, increasing thermal transfer at each level of fabrication, reducing CTE (Coefficient of Thermal Expansion) mismatches, while also decreasing thermal variability with embedded phase change material. These techniques enable the fabrication of more robust, compact electronics. This is a key challenge to implementing the DSI instrument with the most affordable architecture.

The first step to reduce thermally induced fatigue is to increase overall efficiency, therefore reducing the amplitude of power cycling induced thermal variability. This is accomplished through using Gallium Nitride (GaN) transistors for the power amplifiers, which is quickly becoming an industry standard [3]. The next step is moving heat from hot areas quickly to avoid reducing the mean expected lifetimes of adjacent components and devices interconnects. This is done using PCB and housing materials with high thermal conductivity, and well matched CTEs.

The final step in this integrated approach to thermal packaging design is the introduction of a “thermal capacitor”, which effectively low-pass filters heating from power cycling. The thermal capacitor discussed in this paper is PCM (Phase Change Material), which absorbs heat through a phase transition of the material. This concept is not new for ground-based electronics, see for example [4], however, established techniques rely upon gravity and are not applicable to spaceborne instruments. The PCM technology discussed is designed for use in microgravity.

II. HIGH EFFICIENCY ELECTRONICS

GaN (Gallium Nitride) technology shows great promise for RF power amplifiers [5], high power RF and DC switches [6], as well as robust LNAs (Low Noise Amplifiers) [7]. With significantly higher temperature survivability, higher breakdown voltage and lower input impedance than silicon bipolar, along with excellent predicted resistance to total dose radiation [8], GaN is currently the most promising new technology for advancing high-power spaceborne RF electronics.

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III. ADVANCED MATERIALS

Once the most efficient design has been developed, the long-term reliability of the TR module can be improved if the effects of thermal cycling can be mitigated. In the absence of system level active temperature control, which is impractical for distributed electronics such as a phased arrays, closely matching the CTE between materials and quickly moving heat away from hot spots can decrease mechanical stresses on the many interconnects inside of a TR. Controlled Expansion (CE) alloys provide a solution for high thermal conductivity with low CTE, taking the best properties from aluminum and Kovar, respectively, and are discussed below.

A. CTE Matched Silicon Aluminum Alloy

Typical housings for space qualified TR modules are made from either Kovar or 6061 Al. Although Kovar has a coefficient of thermal expansion (CTE) close to those of GaAs and Si, it also possesses a 10x reduction in thermal conductivity and a 3x increase in density compared to 6061 Al. 6061 Al provides improved heat dissipation properties, but has a CTE that is nearly 4x that of Kovar.

A series of controlled expansion (CE) bulk spray deposited Si-Al alloys developed by Sandvik Osprey for electronic packaging applications, are being evaluated for TR housings. These CE housing materials combine a CTE approaching that of Kovar, with a thermal conductivity approaching that of 6061 Al, and a density that is less than that of both materials. The mechanical behavior of select Si-Al alloys was evaluated for space flight applications and direct attachment of active devices, over thermal cycling from -55 to +125°C [10]. The alloy compositions are shown in Table 1, and in Table 2 their CTEs are compared to other materials typically found in TR modules.

Table 1. CE Alloy Compositions

<table>
<thead>
<tr>
<th>Alloy</th>
<th>Composition (wt.%)</th>
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<tbody>
<tr>
<td>CE7</td>
<td>70Si-30Al</td>
</tr>
<tr>
<td>CE9</td>
<td>60Si-40Al</td>
</tr>
<tr>
<td>CE11</td>
<td>50Si-50Al</td>
</tr>
<tr>
<td>CE13</td>
<td>42Si-58Al</td>
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</table>

GaN devices for the transmit chain of the TR module decreases DC power, and its associated thermal dissipation, while slightly increasing transmit power, see Figure 2. This decreases the power consumption of the proposed DESDynl radar array by almost 250W.

The ESS (Energy Storage System) for this transmit chain is crucial to the proper operation of the TR module and radar instrument. A custom ESS has been developed and tested. At ambient temperature and pressure, this ESS is 88% efficient. The design and results of the ESS will be discussed in a separate paper [9].
A typical GaAs die, see Figure 3, was attached to each of four gold-plated CE alloys, using 80Au-20Sn solder at 300°C. The assemblies were exposed to 790 MIL-STD 883G-B thermal cycles (-55 to 125°C) without failure. For detailed results see [10].

Figure 3: Photo of GaAs RF power amplifier attached to CE alloy (gold plated). Samples with CE7, 9, 11 and 13 were exposed to 790 thermal cycles (-55 to 125°C) with zero failures.

These materials have application in high power TR modules for directly attaching bare die parts to the chassis. This eliminates additional manufacturing steps, as well as minimizes the thermal resistance between parts and the module, by reducing interfaces and materials. These alloys may be employed as the overall TR module housing or as a subcircuit carrier in a larger module.

Table 2. CTEs of Various Relevant Electronic Packaging Materials

<table>
<thead>
<tr>
<th>Material</th>
<th>CTE (ppm/°C) 25°C</th>
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<tbody>
<tr>
<td>Al</td>
<td>23.6</td>
</tr>
<tr>
<td>Al2O3</td>
<td>6.7</td>
</tr>
<tr>
<td>CE7</td>
<td>7.2</td>
</tr>
<tr>
<td>CE9</td>
<td>9.1</td>
</tr>
<tr>
<td>CE11</td>
<td>11.4</td>
</tr>
<tr>
<td>CE13</td>
<td>12.2</td>
</tr>
<tr>
<td>Cu</td>
<td>16.6</td>
</tr>
<tr>
<td>GaAs</td>
<td>5.4-5.72</td>
</tr>
<tr>
<td>Si</td>
<td>2.3-4.7</td>
</tr>
</tbody>
</table>

B. Carbon Impregnated PCB

For devices that must mount to a PCB, as opposed to the direct die attach, discussed above, efficient heat removal can still be critical.

Large FPGAs, such as the Xilinx V5, can develop significant localized heat that must be removed. Similarly, packaged high power RF amplifiers, or transistors can generate significant thermal cycling stresses on surrounding components (the RF power devices themselves are typically designed to survive and are more robust than the supporting electronics.) To move the heat of PCB mounted components, and to reduce the risk of over stressing vias, carbon impregnated PCB material from Stablcor™ was investigated alongside the best more standard materials.

A test structure, which includes FPGA packages, microstrip, stripline, buried and blind vias, was designed and fabricated using selected PCB materials. The temperature rise, due to active components, was monitored in several locations (noted 1,2,3). The results and materials modeled are shown in Figure 4. Those highlighted in green border have been fabricated and are being tested for stability of RF performance of stripline and microstrip, over power cycling, and reliability of vias and FPGA attachment.

Figure 4: Modeled thermal performance of several PCB layers, or stacks. Rogers 6002, Arlon TC350, Rogers4003, with and without Stablcor™.

IV. PCM: THERMAL CAPACITOR

PCM, or phase change material, absorbs significant amounts of heat through the phase transition of its constituent material. This concept is not new and has been used to cool CPUs [4], however these heat sinks require gravity. ESLI (Energy Science Laboratories, Inc) attempts to overcome this limitation through incorporating a carbon fiber matrix to distribute the heat throughout the PCM without requiring gravity.

The PCM thermal capacitor allows densely packed, high power TR modules to operate at nearly a constant temperature over defined periods of operation. Our nominal design is for a 5 minute period, with a 50% duty cycle, and a maximum temperature of 50°C. Eicosane paraffin wax is used as the material because of its high latent heat capacity and melting point temperature of 36°C, allowing margin for thermal resistance of the TR module. The latent heat storage of the
PCM was experimentally determined to be 50.5kJ, as compared to its design requirement of 48.7kJ, see Figure 5.

V. INTEGRATED TR MODULE

Each of these technologies is being integrated into a flight-like TR module, targeted at the DESDynI radar, capable of more than 100W transmit power using the high efficiency GaN PA, high thermal conductivity using the advanced materials, high peak thermal capacity using the PCM and heat spreader, with increased reliability through lower thermal variability and controlled expansion materials.

Final design and thermal analyses of the standard technology integrated TR module are currently underway. The TR module, see Figure 7, includes a >65% efficient transmitter, 90% efficient power supply, and a direct thermal path to space, with the “floor” of the module designed as the unit’s actual thermal radiator.

An exploded view of the TR module, with the “floor” shown facing down, can be seen in Figure 6. Both the standard packaging and advanced packaging versions have the same build, except the advanced packaging version has two additional boards between the PCBs (brown) and chassis (blue). These are the 2-phase heat spreader and PCM thermal capacitor, which spread the heat from the power amplifier’s transistors and absorb this heat in the PCM, reducing heating of the overall module by more than 50%.

The transparent floor of the standard module is shown facing up, in Figure 8. This is the unit’s thermal radiator.

The advanced version of the integrated TR module is shown in Figure 9. It includes all of the aspects of the advanced high power TR module development accepted into the proposed DESDynI TRM, as well as the embedded PCM, 2-phase heat spreader and select chassis components machined from controlled expansion alloys. The inclusion of these technologies will increase the reliability of the module’s interconnects, by reducing overall thermal cycling by at least...
50%, and by reducing interconnect fatigue through the use of the CTE alloys.

Both the flight version and the advanced packaging versions of this TR are anticipated to be prototyped, tested and compared by the end of the calendar year.

VI. SUMMARY

Advanced materials and fabrication techniques are being investigated to improve performance and reliability of high power TR modules. Several promising technologies exist to reduce waste heat, increase thermal conductivity, reduce mechanical stresses through CTE matching, and reducing thermal cycling extremes through thermal capacitors (PCM). These technologies have been tested separately, and are in the process of being integrated into a test unit.

Successful integration of these technologies allows for packaging of higher power density electronics, while maintaining reliability. This work helps to enable more cost effective radar architectures for earth remote sensing, such as SweepSAR, which is being considered for the proposed DESDynI radar.

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REFERENCES